

www.vishay.com

Vishay Siliconix

Automotive P-Channel 30 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	-30				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.0044				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.0071				
I _D (A)	-60				
Configuration	Single				

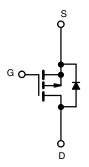
FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS COMPLIANT HALOGEN FREE



P-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and halogen-free	SQJ407EP (for detailed order number please see www.vishay.com/doc?79771)

PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V_{DS}	-30	V	
Gate-source voltage		V_{GS}	± 20	7	
Continuous drain current	T _C = 25 °C a	ı	-60		
Continuous drain current	T _C = 125 °C	I _D	-56		
Continuous source current (diode conduction) ^a		I _S	-60	Α	
Pulsed drain current ^b		I _{DM}	-155		
Single pulse avalanche current	1 0.1 ml l	I _{AS}	-41		
Single pulse avalanche energy	L = 0.1 mH	E _{AS}	84	mJ	
Maximum power dissipation ^b	T _C = 25 °C	D	68	W	
	T _C = 125 °C	P_{D}	22		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature) d, e		•	260		

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient PC	CB mount ^c	R_{thJA}	68	°C/W
Junction-to-case (drain)		R_{thJC}	2.2	C/VV

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (www.vishay.com/doc?73257). For PowerPAK SO-8L, the end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components



www.vishay.com

Vishay Siliconix

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static		<u> </u>					
Drain-source breakdown voltage	V _{DS}	V _{GS}	= 0, I _D = -250 μA	-30		-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	V _{GS} , I _D = -250 μA	-1.5	-2.0	-2.5	ľ
Gate-source leakage	I _{GSS}	V _{DS} =	$0 \text{ V}, \text{ V}_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA
		V _{GS} = 0 V	V _{DS} = -30 V	-	-	-1	
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = -30 V, T _J = 125 °C	=	-	-50	μΑ
		V _{GS} = 0 V	V _{DS} = -30 V, T _J = 175 °C	-	-	-200	
On-state drain current ^a	I _{D(on)}	V _{GS} = -10 V	V _{DS} ≥ -5 V	-30	-	-	Α
		V _{GS} = -10 V	I _D = -10 A	-	0.0036	0.0044	
Drain actives on state resistance 3	В	V _{GS} = -10 V	I _D = -10 A, T _J = 125 °C	-	-	0.0060	Ω
Drain-source on-state resistance ^a	$R_{DS(on)}$	V _{GS} = -10 V	I _D = -10 A, T _J = 175 °C	-	-	0.0068	1 12
		V _{GS} = -4.5 V	I _D = -6 A	-	0.0059	0.0071	
Forward transconductance b	9 _{fs}	V _{DS} =	-15 V, I _D = -10 A	-	60	-	S
Dynamic ^b					•		,
Input capacitance	C _{iss}			-	8200	10 700	
Output capacitance	C _{oss}	V _{GS} = 0 V	V _{DS} = -25 V, f = 1 MHz	-	950	1300	pF
Reverse transfer capacitance	C _{rss}	1		-	785	1050	
Total gate charge ^c	Qg			-	169	260	
Gate-source charge ^c	Q _{gs}	V _{GS} = -10 V	$V_{DS} = -15 \text{ V}, I_{D} = -5 \text{ A}$	-	24	-	nC
Gate-drain charge ^c	Q _{gd}	1		-	32	-	
Gate resistance	R_g		f = 1 MHz	0.5	1.05	1.6	Ω
Turn-on delay time ^c	t _{d(on)}			-	23	35	
Rise time ^c	t _r	V _{DD} :	= -15 V, R_L = 3 Ω	-	19	30	
Turn-off delay time ^c	t _{d(off)}		$I_{\rm GEN} = -10$ V, $R_{\rm g} = 1 \Omega$	-	72	120	ns
Fall time ^c	t _f			-	14	25	
Source-Drain Diode Ratings and Charac	teristics b	•					
Pulsed current ^a	I _{SM}			-	-	-155	Α
Forward voltage	V _{SD}	I _F =	-10 A, V _{GS} = 0 V	-	-0.75	-1.2	V
Body diode reverse recovery time	t _{rr}			-	39	90	ns
Body diode reverse recovery charge	Q _{rr}	1		-	45	100	nC
Reverse recovery fall time	t _a	I _F = 10	A, di/dt = 100 A/μs	-	22	-	
Reverse recovery rise time	t _b	7		_	19	-	ns
					<u> </u>	l	

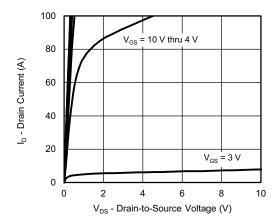
Notes

- f. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- g. Guaranteed by design, not subject to production testing
- h. Independent of operating temperature

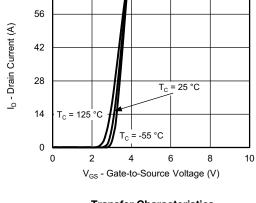
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

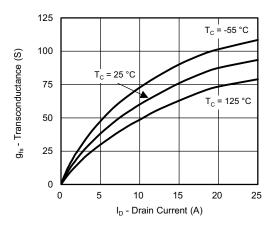


Output Characteristics

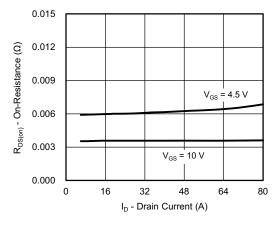


70

Transfer Characteristics

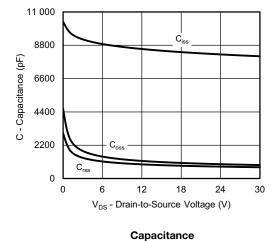


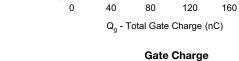
Transconductance



On-Resistance vs. Drain Current

200





10

8

6

2

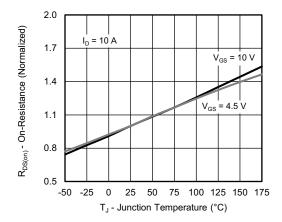
0

I_D = 5 Å V_{DS} = 18

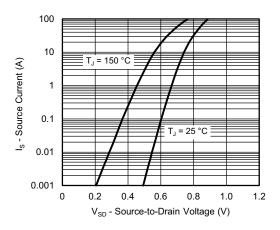
V_{GS} - Gate-to-Source Voltage (V)



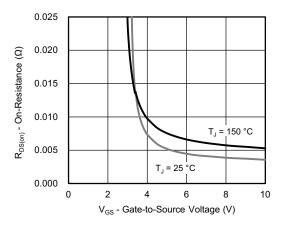
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



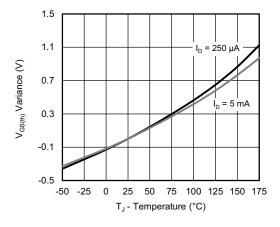
On-Resistance vs. Junction Temperature



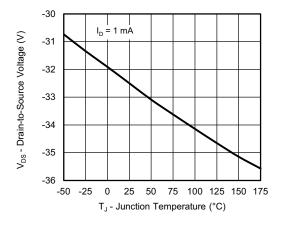
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage

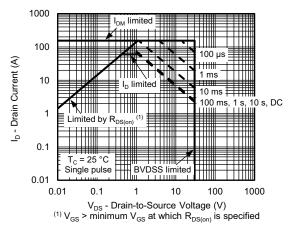


Drain-Source Breakdown vs. Junction Temperature

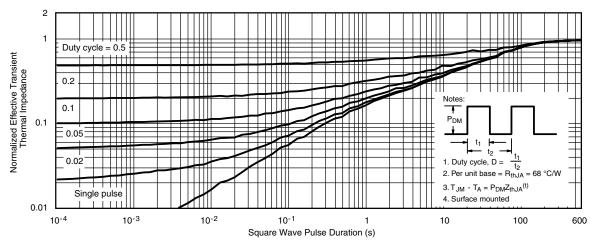
For technical questions, contact: automostech



THERMAL RATINGS (T_C = 25 °C, unless otherwise noted)



Safe Operating Area

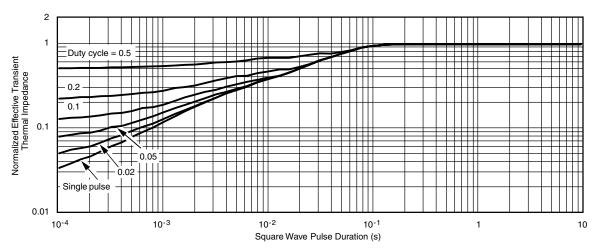


Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix



THERMAL RATINGS (T_C = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62806.



PowerPAK® SO-8L Case Outline 2



Vishay Siliconix

DIM.	MILLIMETERS			INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	1.00	1.07	1.14	0.039	0.042	0.045	
A1	0.00	-	0.127	0.00	-	0.005	
b	0.33	0.41	0.48	0.013	0.016	0.019	
b1	0.44	0.51	0.58	0.017	0.020	0.023	
b2	4.80	4.90	5.00	0.189	0.193	0.197	
b3		0.094		0.004			
b4		0.47			0.019		
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	5.00	5.13	5.25	0.197	0.202	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D3	1.63	1.73	1.83	0.064	0.068	0.072	
е		1.27 BSC		0.050 BSC			
Е	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	2.75	2.85	2.95	0.108	0.112	0.116	
F	-	-	0.15	-	-	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
K		0.51			0.020		
W	0.23		0.009				
W1	0.41			0.016			
W2	2.82			0.111			
W3		2.96			0.117		
θ	0°	-	10°	0°	-	10°	

ECN: C21-1498-Rev. C, 01-Nov-2021

DWG: 6044

Note

• Millimeters will govern



RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L SINGLE



Recommended Minimum Pads Dimensions in mm (inches)



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.